

DATA SHEET

BFG135

NPN 7GHz wideband transistor

Product specification

1995 Sep 13



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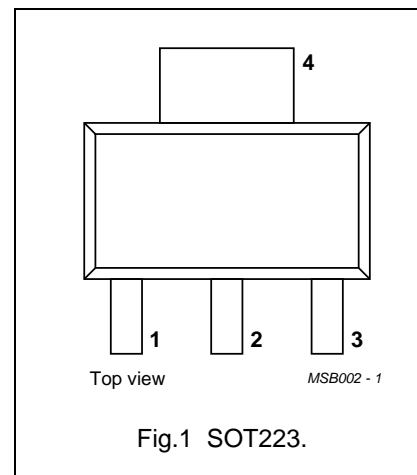
DESCRIPTION

NPN silicon planar epitaxial transistor in a plastic SOT223 envelope, intended for wideband amplifier applications. The small emitter structures, with integrated emitter-ballasting resistors, ensure high output voltage capabilities at a low distortion level.

The distribution of the active areas across the surface of the device gives an excellent temperature profile.

PINNING

PIN	DESCRIPTION
1	emitter
2	base
3	emitter
4	collector



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{CB0}	collector-base voltage	open emitter	–	–	25	V
V_{CE0}	collector-emitter voltage	open base	–	–	15	V
I_C	DC collector current		–	–	150	mA
P_{tot}	total power dissipation	up to $T_s = 145\text{ °C}$ (note 1)	–	–	1	W
h_{FE}	DC current gain	$I_C = 100\text{ mA}$; $V_{CE} = 10\text{ V}$; $T_j = 25\text{ °C}$	80	130	–	
f_T	transition frequency	$I_C = 100\text{ mA}$; $V_{CE} = 10\text{ V}$; $f = 1\text{ GHz}$; $T_{amb} = 25\text{ °C}$	–	7	–	GHz
G_{UM}	maximum unilateral power gain	$I_C = 100\text{ mA}$; $V_{CE} = 10\text{ V}$; $f = 500\text{ MHz}$; $T_{amb} = 25\text{ °C}$	–	16	–	dB
		$I_C = 100\text{ mA}$; $V_{CE} = 10\text{ V}$; $f = 800\text{ MHz}$; $T_{amb} = 25\text{ °C}$	–	12	–	dB
V_o	output voltage	$d_{im} = -60\text{ dB}$; $I_C = 100\text{ mA}$; $V_{CE} = 10\text{ V}$; $R_L = 75\text{ }\Omega$; $T_{amb} = 25\text{ °C}$; $f_{(p+q-r)} = 793.25\text{ MHz}$	–	850	–	mV

LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CB0}	collector-base voltage	open emitter	–	25	V
V_{CE0}	collector-emitter voltage	open base	–	15	V
V_{EBO}	emitter-base voltage	open collector	–	2	V
I_C	DC collector current		–	150	mA
P_{tot}	total power dissipation	up to $T_s = 145\text{ °C}$ (note 1)	–	1	W
T_{stg}	storage temperature		–65	150	°C
T_j	junction temperature		–	175	°C

Note

- T_s is the temperature at the soldering point of the collector tab.

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	THERMAL RESISTANCE
$R_{th\ j-s}$	thermal resistance from junction to soldering point	up to $T_s = 145\text{ °C}$ (note 1)	30 K/W

Note

- T_s is the temperature at the soldering point of the collector tab.

CHARACTERISTICS

$T_j = 25\text{ °C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_{CBO}	collector cut-off current	$I_E = 0; V_{CB} = 10\text{ V}$	–	–	1	μA
h_{FE}	DC current gain	$I_C = 100\text{ mA}; V_{CE} = 10\text{ V}$	80	130	–	
C_c	collector capacitance	$I_E = I_e = 0; V_{CB} = 10\text{ V}; f = 1\text{ MHz}$	–	2	–	pF
C_e	emitter capacitance	$I_C = I_c = 0; V_{EB} = 0.5\text{ V}; f = 1\text{ MHz}$	–	7	–	pF
C_{re}	feedback capacitance	$I_C = 0; V_{CE} = 10\text{ V}; f = 1\text{ MHz}$	–	1.2	–	pF
f_T	transition frequency	$I_C = 100\text{ mA}; V_{CE} = 10\text{ V}; f = 1\text{ GHz}; T_{amb} = 25\text{ °C}$	–	7	–	GHz
G_{UM}	maximum unilateral power gain	$I_C = 100\text{ mA}; V_{CE} = 10\text{ V}; f = 500\text{ MHz}; T_{amb} = 25\text{ °C}$	–	16	–	dB
		$I_C = 100\text{ mA}; V_{CE} = 10\text{ V}; f = 800\text{ MHz}; T_{amb} = 25\text{ °C}$	–	12	–	dB
V_o	output voltage	note 1	–	900	–	mV
		note 2	–	850	–	mV
d_2	second order intermodulation distortion	$I_C = 90\text{ mA}; V_{CE} = 10\text{ V}; V_O = 50\text{ dBmV}; T_{amb} = 25\text{ °C}; f_{(p+q)} = 450\text{ MHz}; f_p = 50\text{ MHz}; f_q = 400\text{ MHz}$	–	–58	–	dB
		$I_C = 90\text{ mA}; V_{CE} = 10\text{ V}; V_O = 50\text{ dBmV}; T_{amb} = 25\text{ °C}; f_{(p+q)} = 810\text{ MHz}; f_p = 250\text{ MHz}; f_q = 560\text{ MHz}$	–	–53	–	dB

Notes

- $d_{im} = -60\text{ dB}$ (DIN 45004B); $I_C = 100\text{ mA}; V_{CE} = 10\text{ V}; R_L = 75\ \Omega; T_{amb} = 25\text{ °C}; V_p = V_o$ at $d_{im} = -60\text{ dB}; f_p = 445.25\text{ MHz}; V_q = V_o - 6\text{ dB}; f_q = 453.25\text{ MHz}; V_r = V_o - 6\text{ dB}; f_r = 455.25\text{ MHz};$ measured at $f_{(p+q-r)} = 443.25\text{ MHz}$.
- $d_{im} = -60\text{ dB}$ (DIN 45004B); $I_C = 100\text{ mA}; V_{CE} = 10\text{ V}; R_L = 75\ \Omega; T_{amb} = 25\text{ °C}; V_p = V_o$ at $d_{im} = -60\text{ dB}; f_p = 795.25\text{ MHz}; V_q = V_o - 6\text{ dB}; f_q = 803.25\text{ MHz}; V_r = V_o - 6\text{ dB}; f_r = 805.25\text{ MHz};$ measured at $f_{(p+q-r)} = 793.25\text{ MHz}$.

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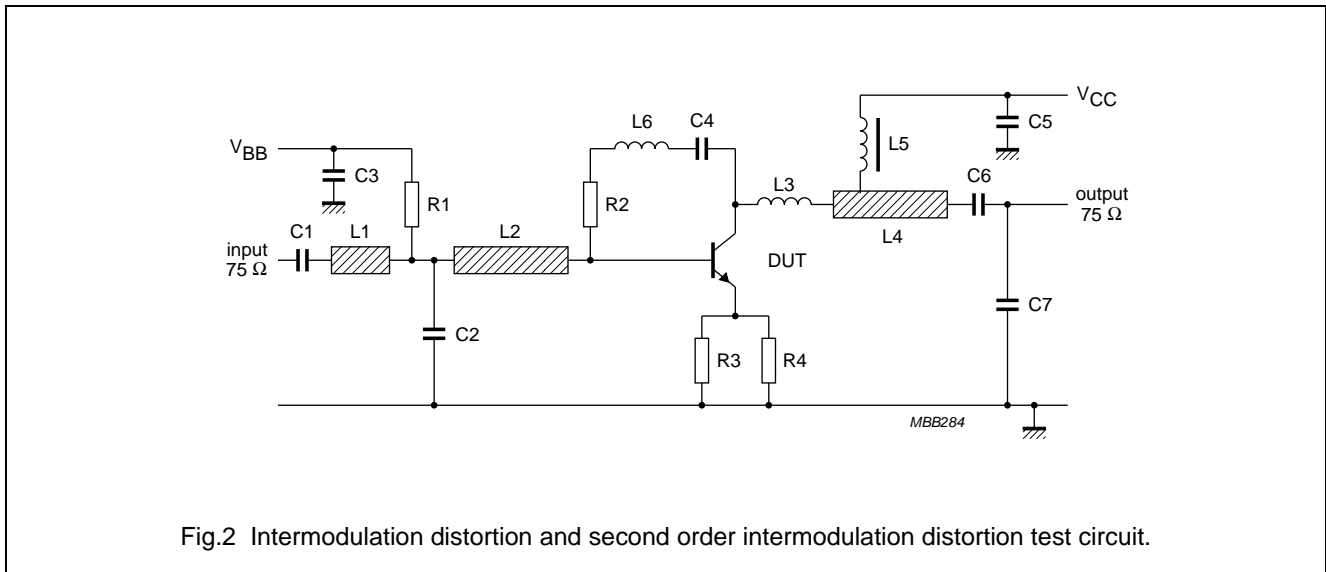


Fig.2 Intermodulation distortion and second order intermodulation distortion test circuit.

List of components (see test circuit)

DESIGNATION	DESCRIPTION	VALUE	UNIT	DIMENSIONS	CATALOGUE NO.
C1, C3, C5, C6	multilayer ceramic capacitor	10	nF		2222 590 08627
C2, C7	multilayer ceramic capacitor	1	pF		2222 851 12108
C4 (note 1)	miniature ceramic plate capacitor	10	nF		2222 629 08103
L1	microstripline	75	Ω	length 7 mm; width 2.5 mm	
L2	microstripline	75	Ω	length 22mm; width 2.5 mm	
L3 (note 1)	1.5 turns 0.4 mm copper wire			int. dia. 3 mm; winding pitch 1 mm	
L4	microstripline	75	Ω	length 19 mm; width 2.5 mm	
L5	Ferroxcube choke	5	μ H		3122 108 20153
L6 (note 1)	0.4 mm copper wire	\approx 25	nH	length 30 mm	
R1	metal film resistor	10	k Ω		2322 180 73103
R2 (note 1)	metal film resistor	200	Ω		2322 180 73201
R3, R4	metal film resistor	27	Ω		2322 180 73279

Note

- Components C4, L3, L6 and R2 are mounted on the underside of the PCB.
The circuit is constructed on a double copper-clad printed circuit board with PTFE dielectric ($\epsilon_r = 2.2$); thickness $1/16$ inch; thickness of copper sheet $1/32$ inch.

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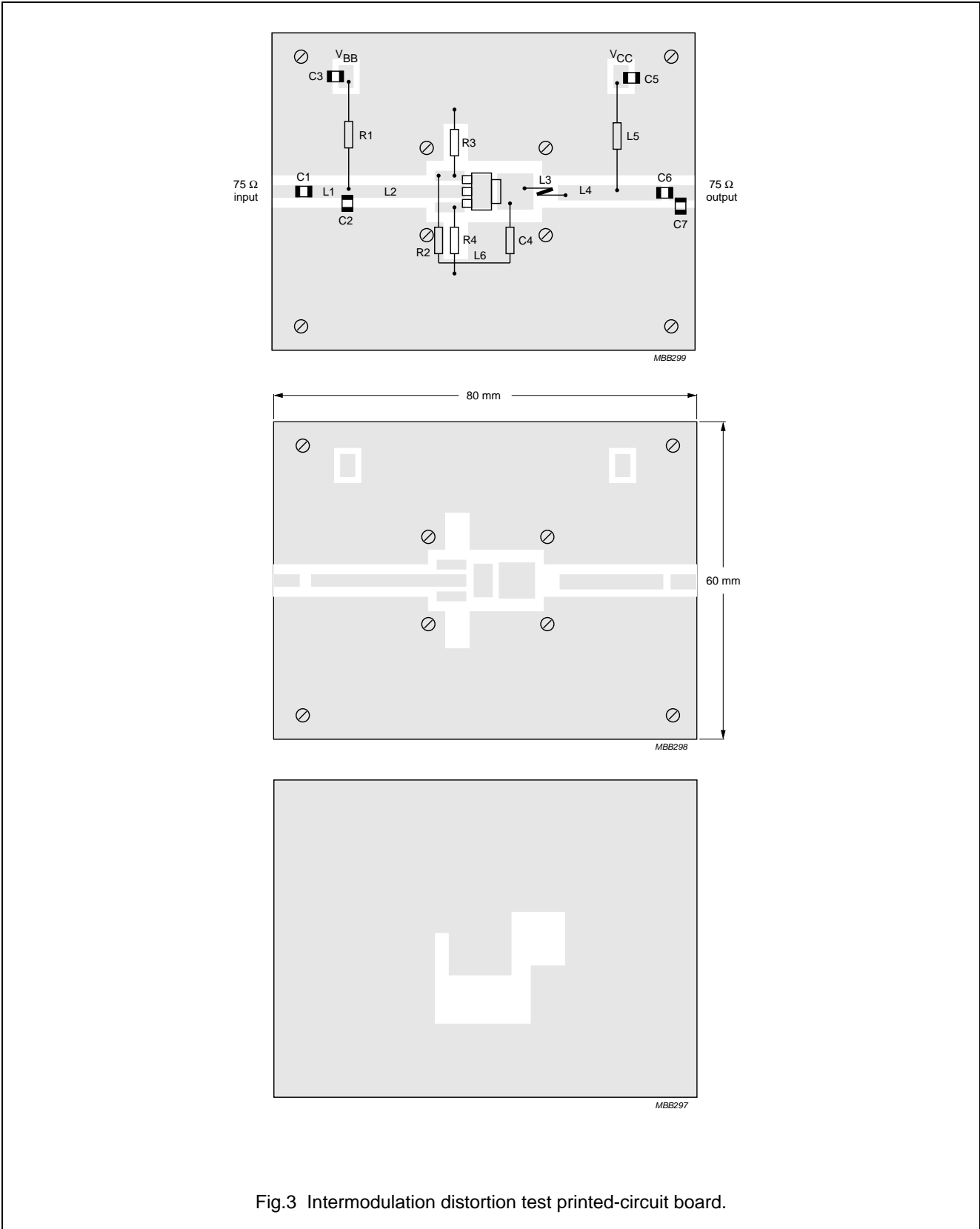
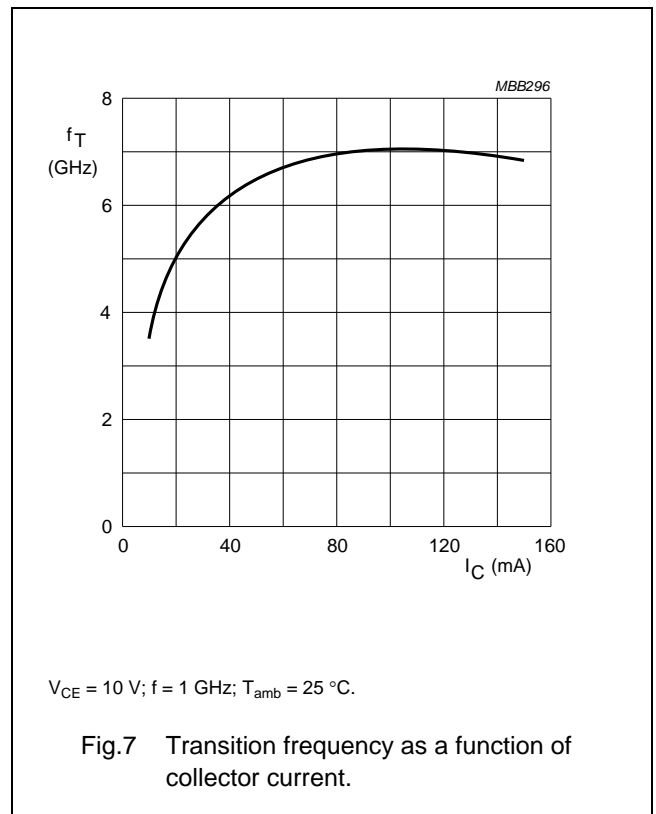
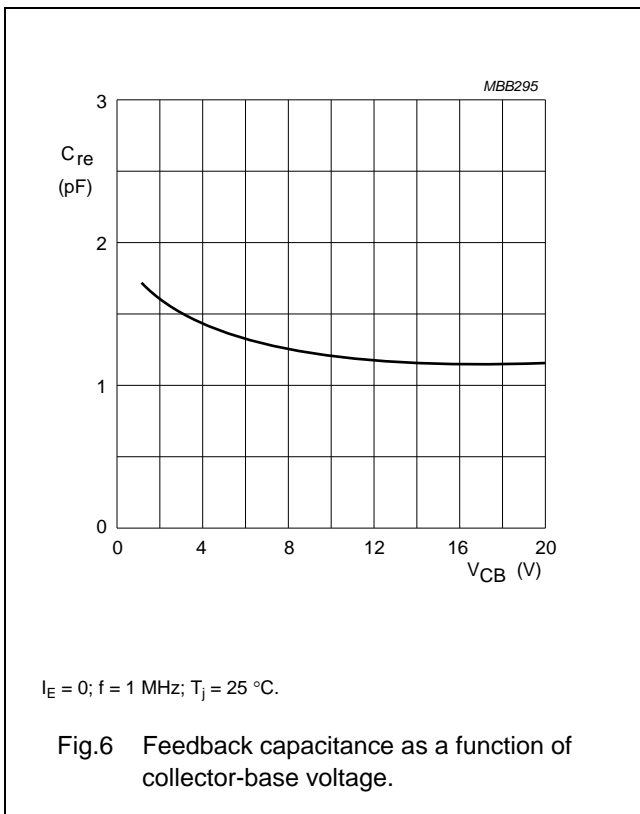
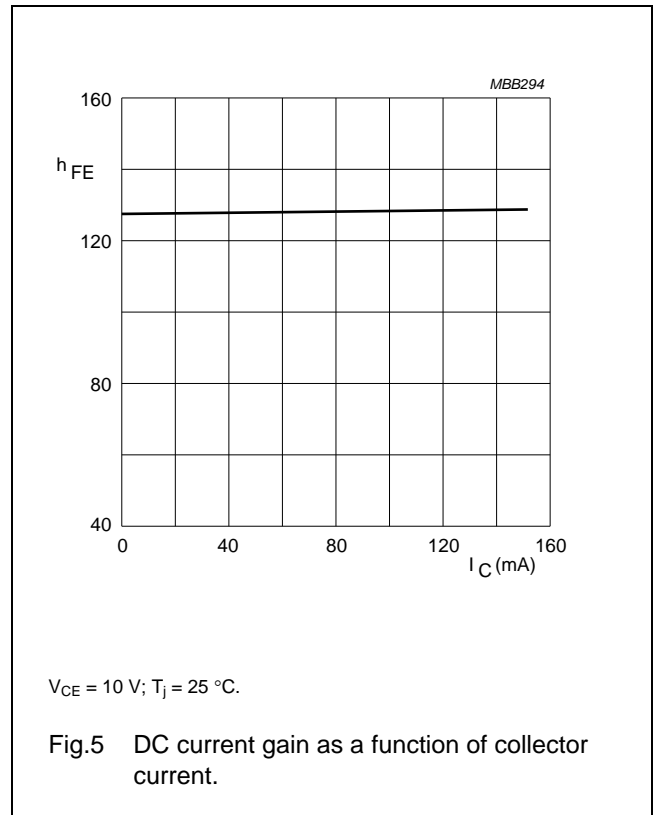
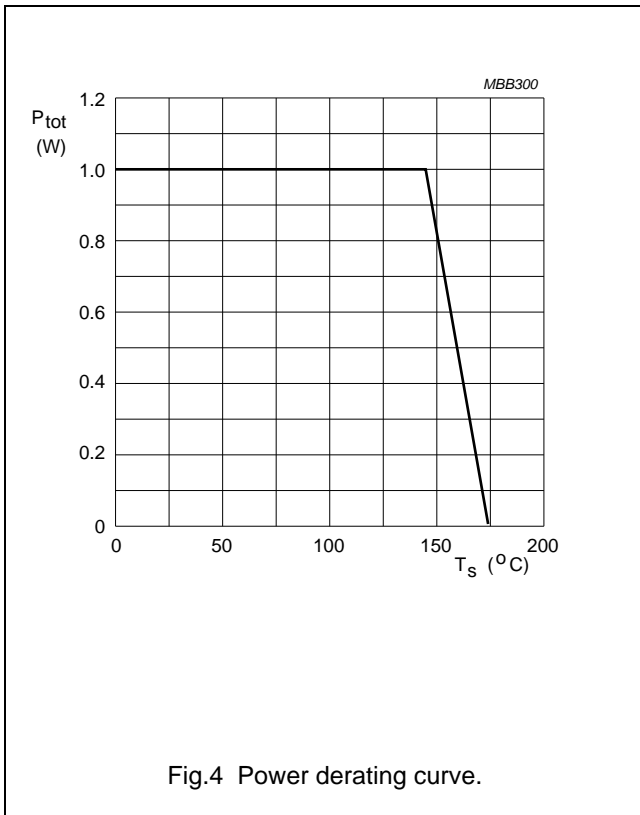


Fig.3 Intermodulation distortion test printed-circuit board.

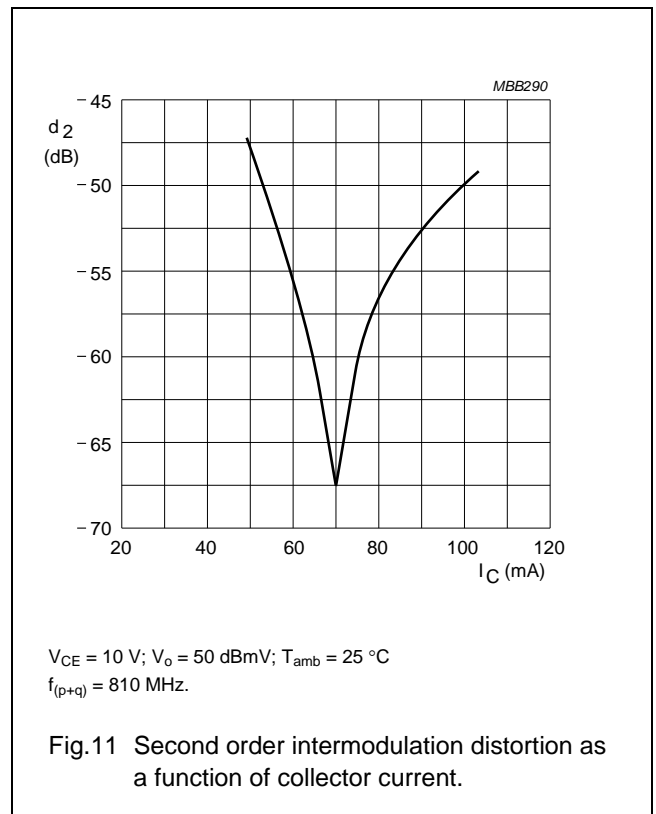
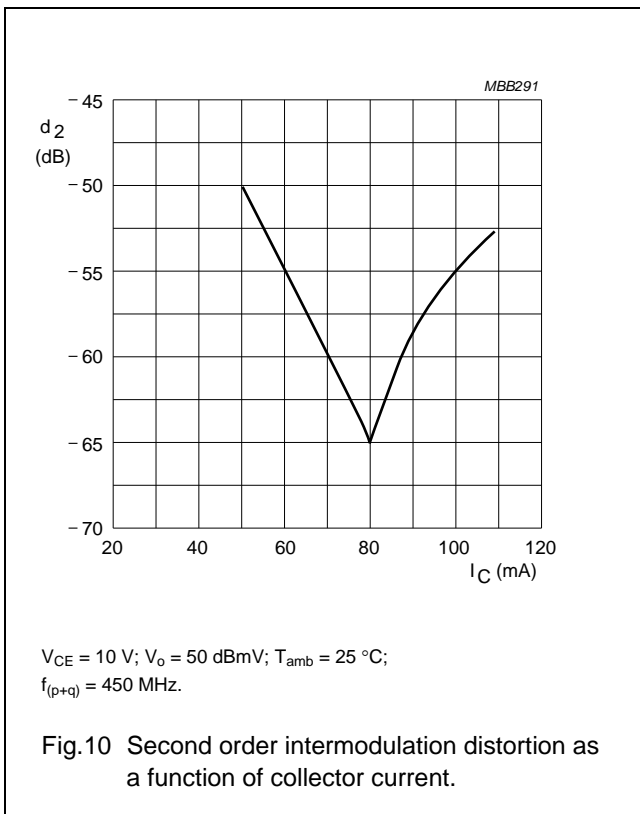
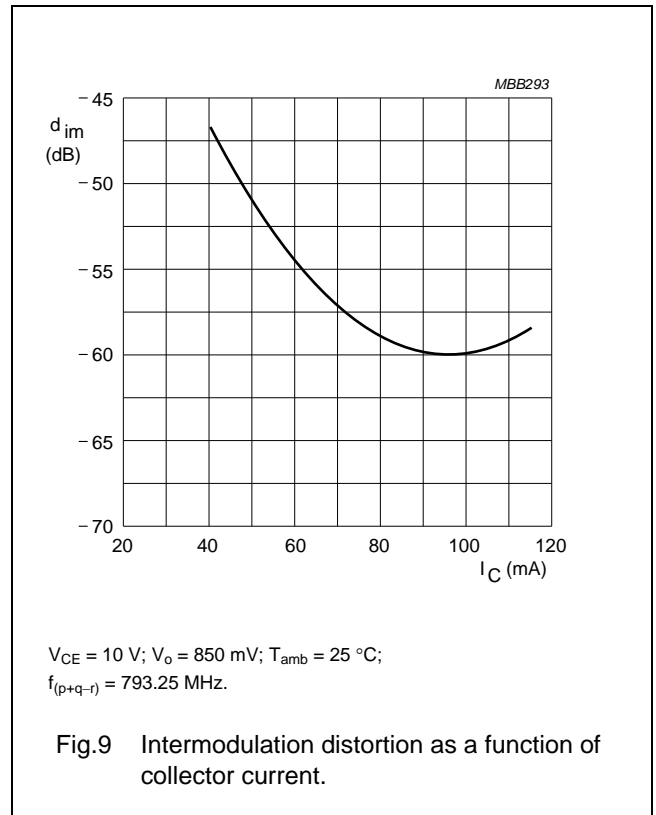
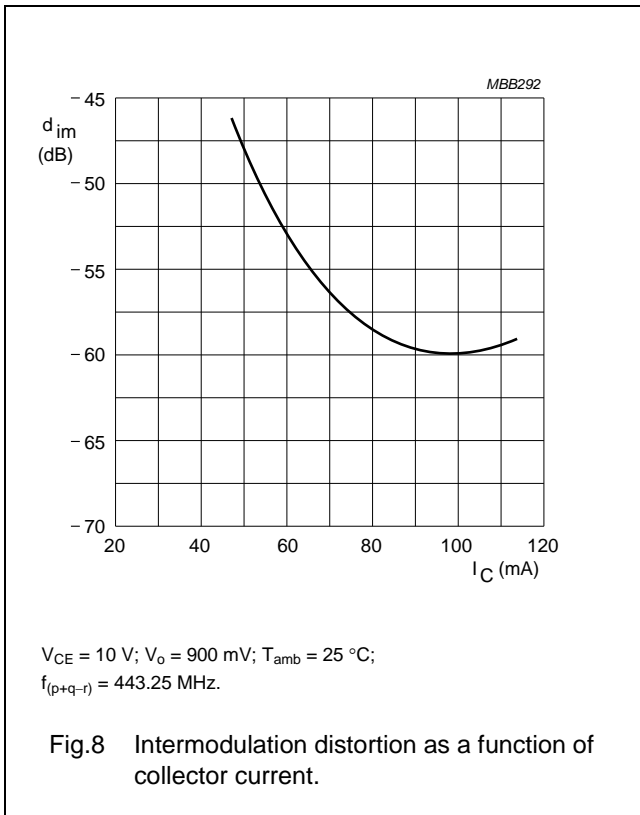
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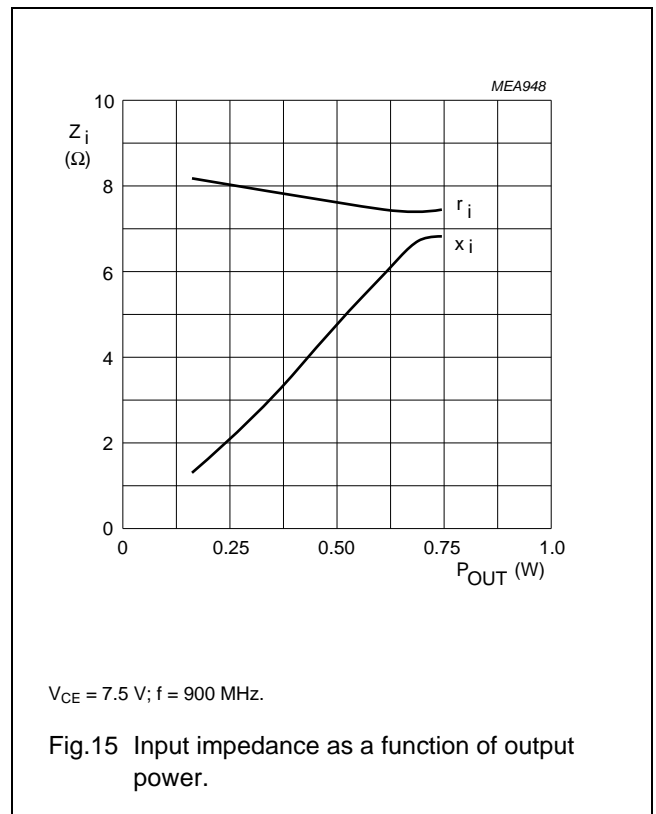
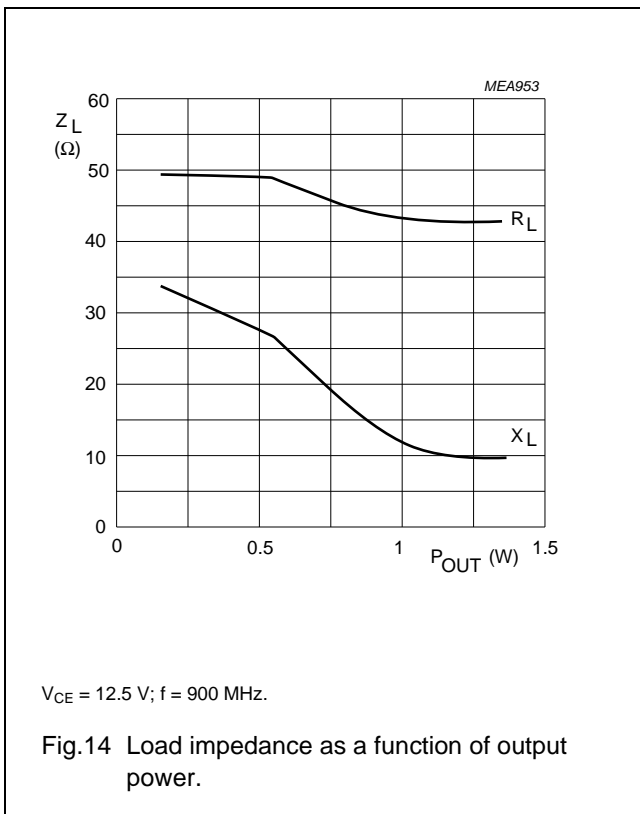
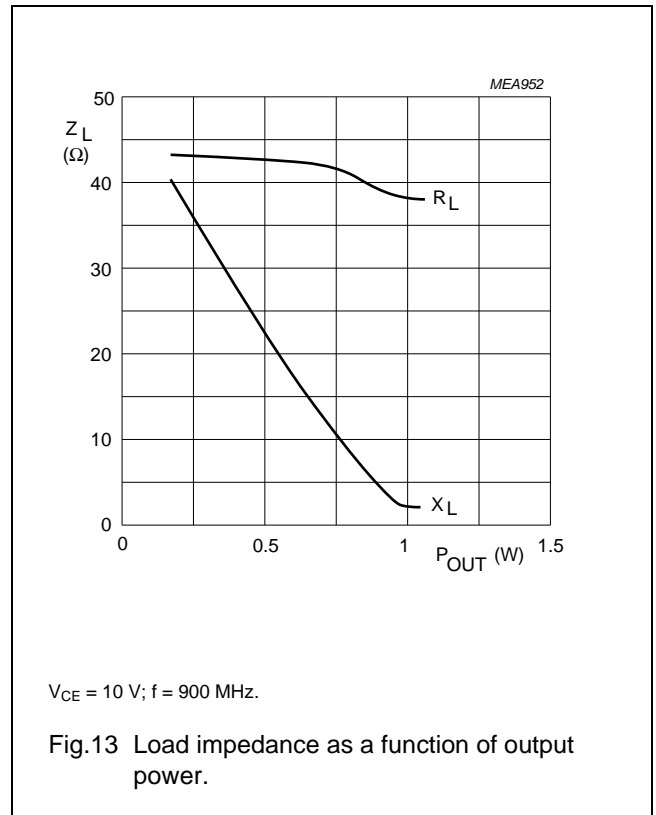
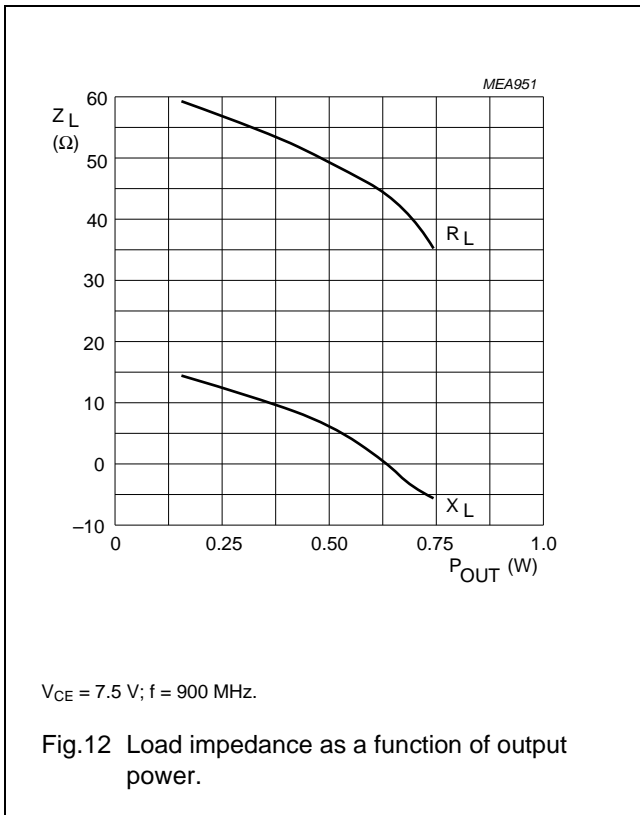
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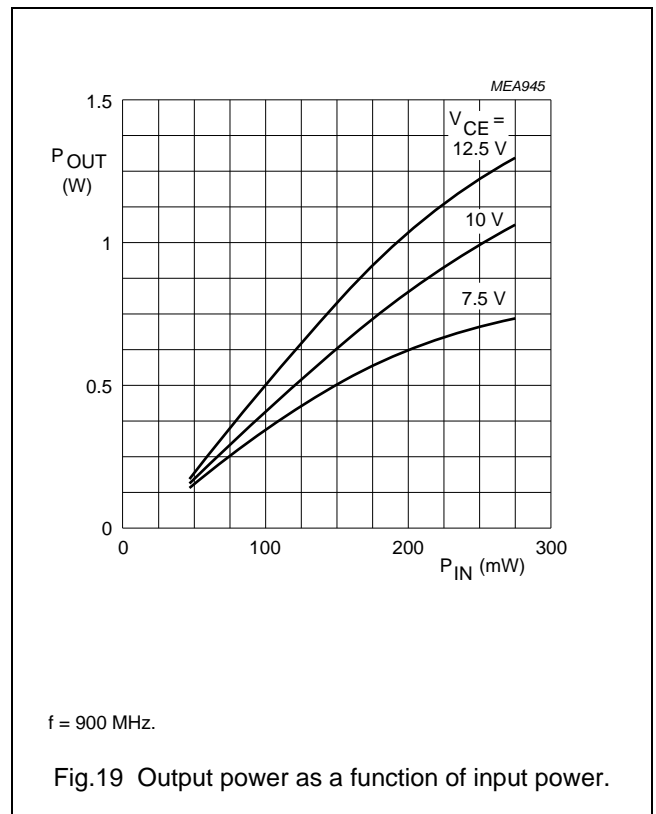
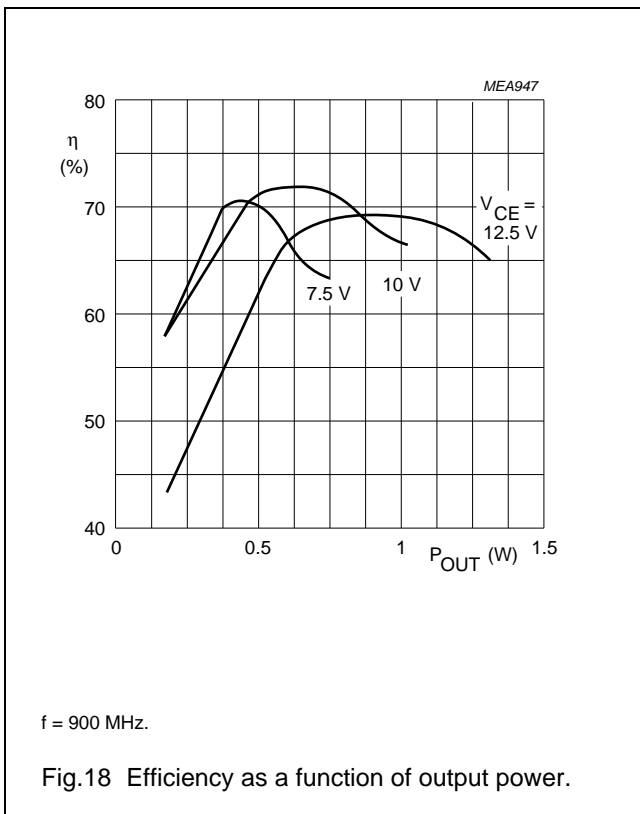
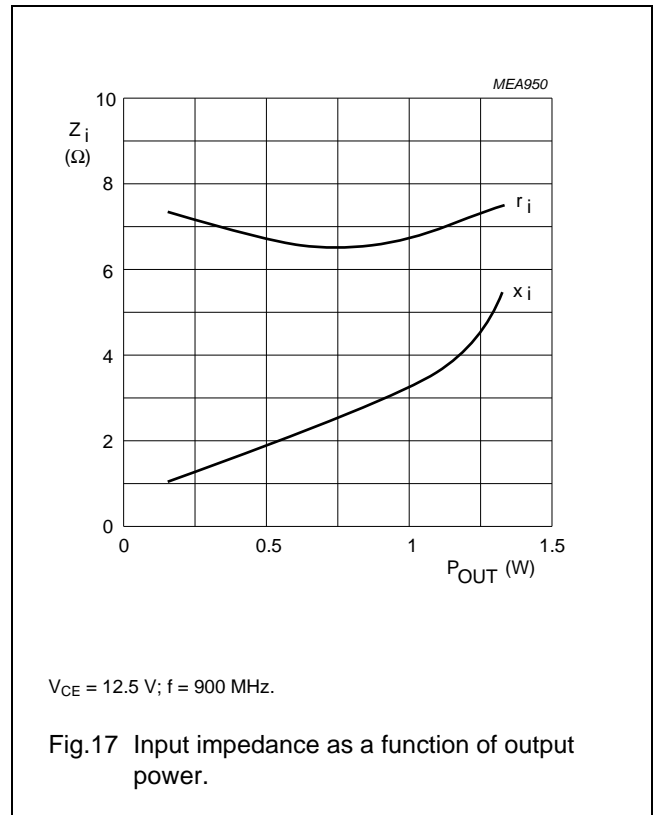
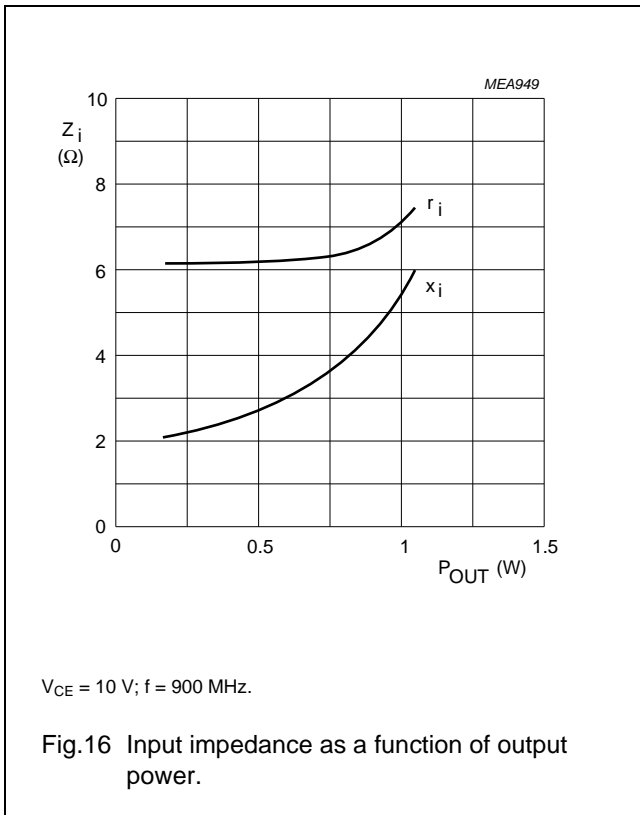
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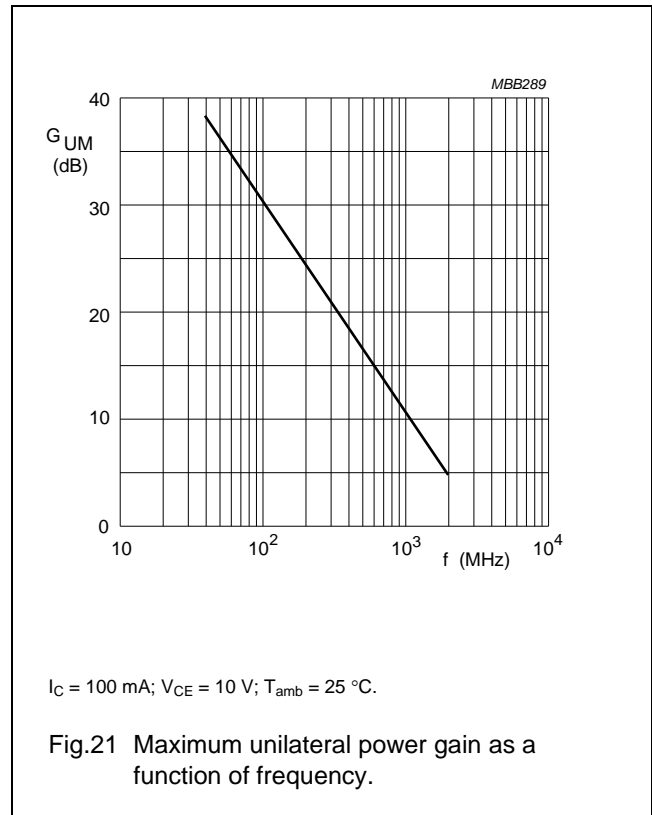
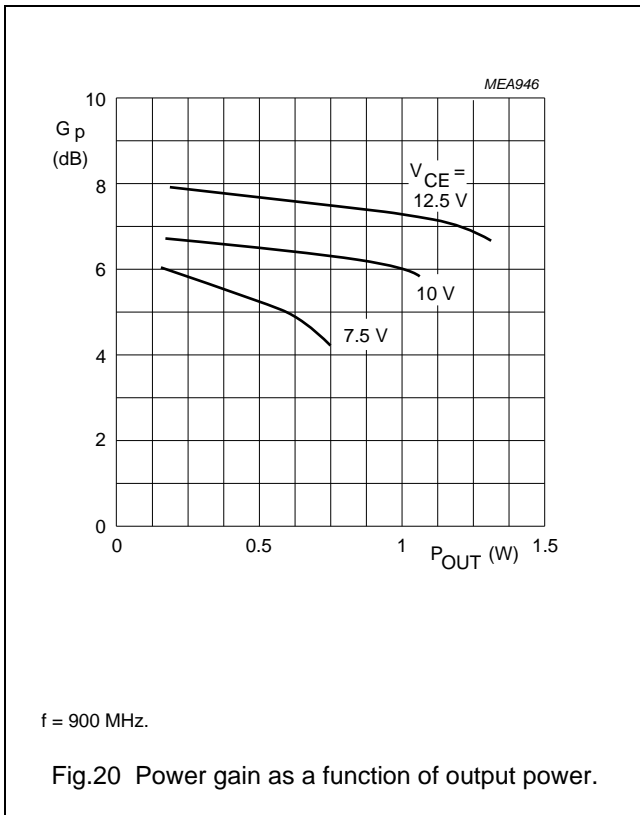
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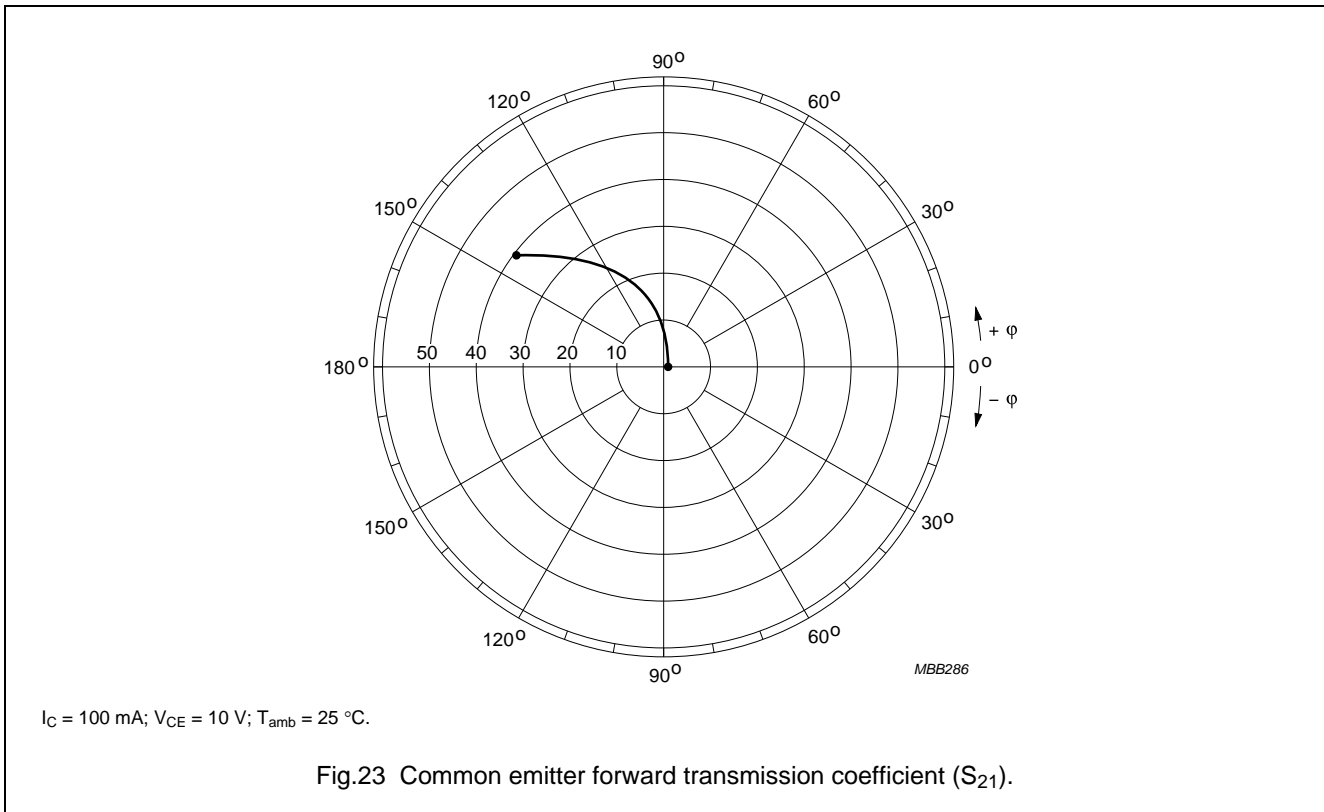
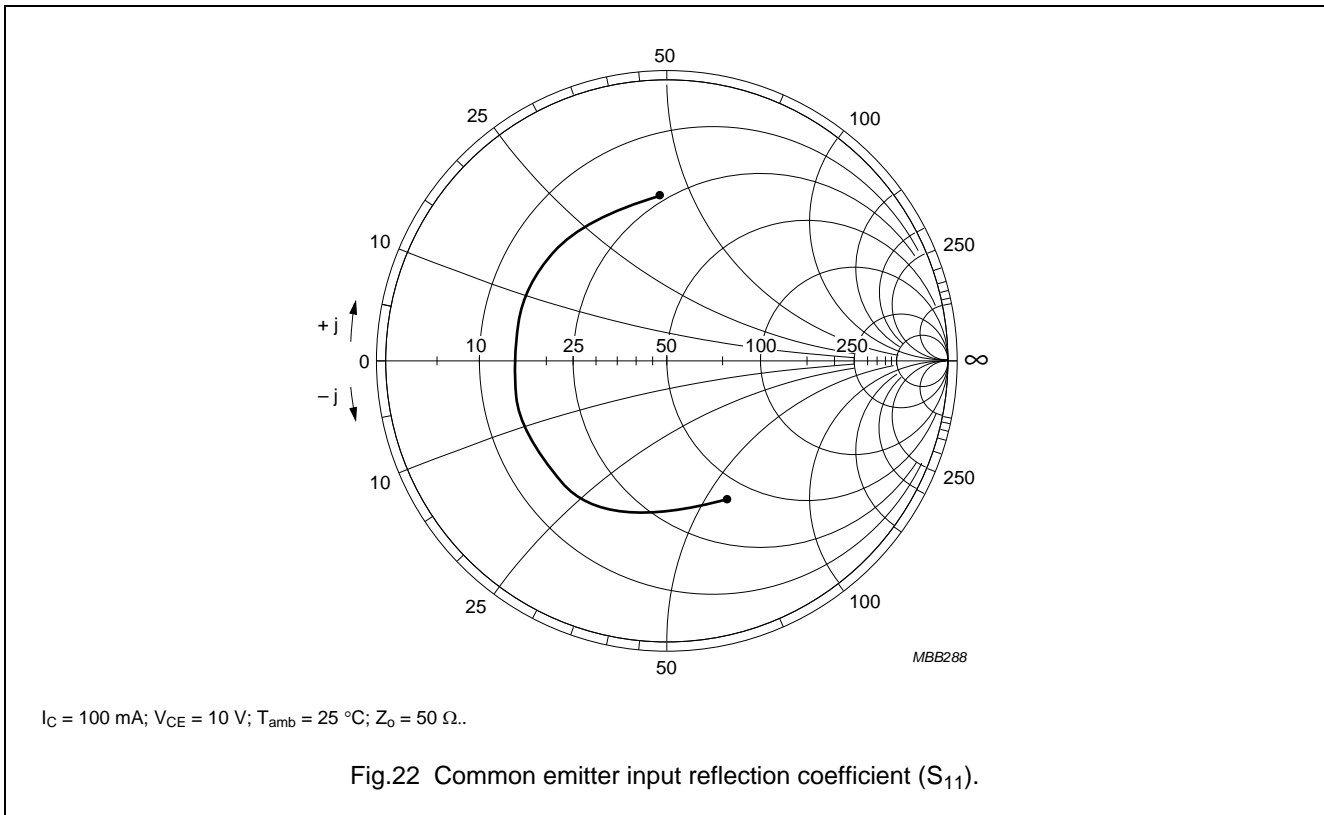
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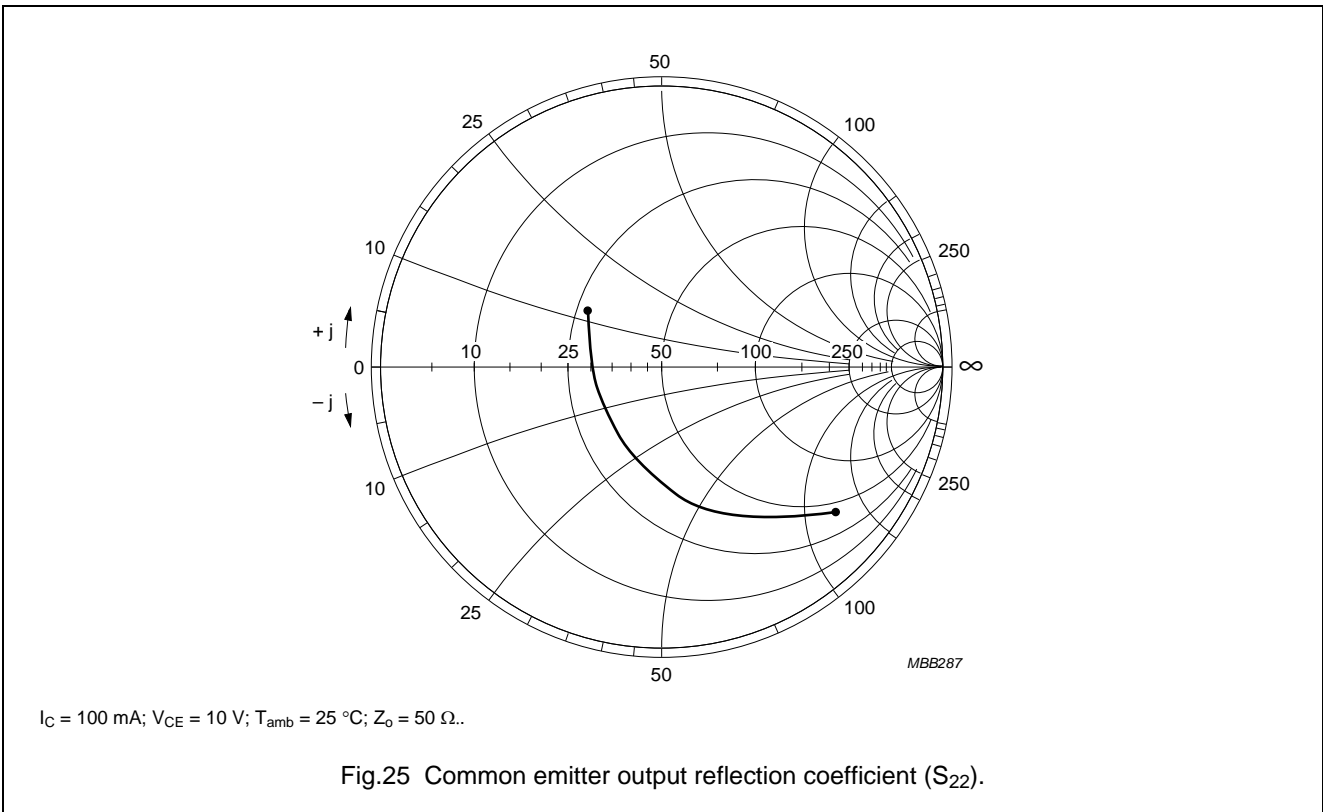
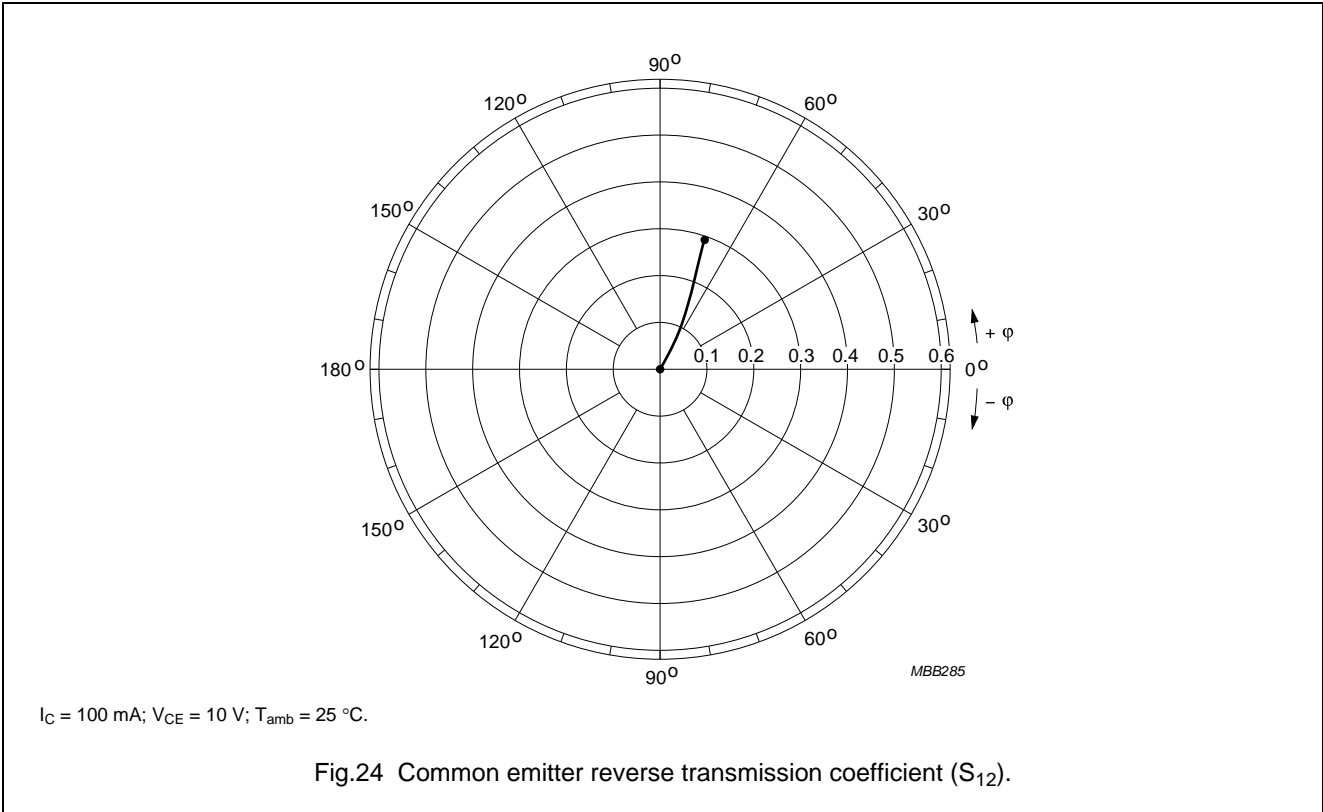
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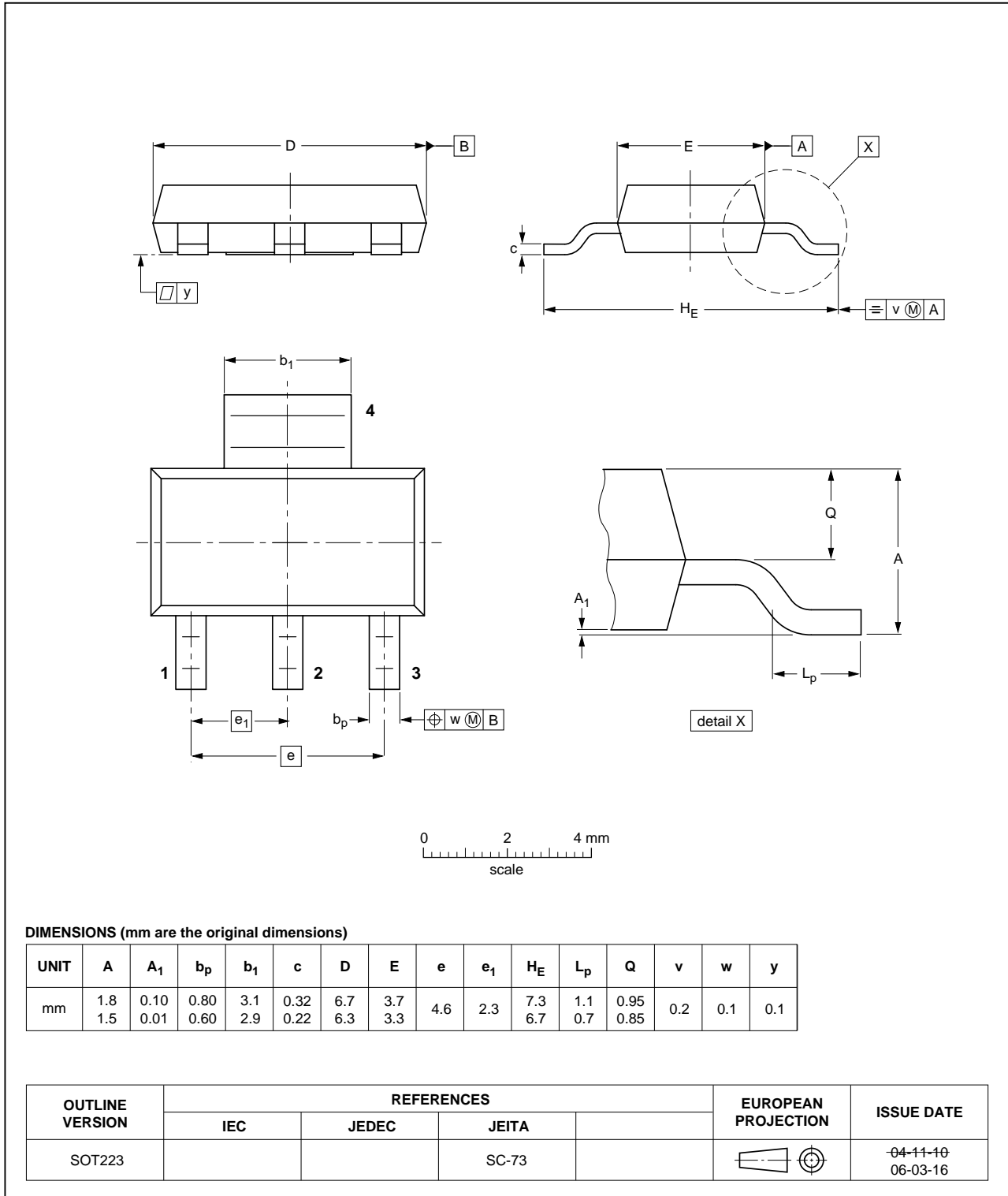
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PACKAGE OUTLINE

Plastic surface-mounted package with increased heatsink; 4 leads

SOT223



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DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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